

SKKT 250, SKKH 250



SEMIPACK® 3

Thyristor / Diode Modules

SKKH 250

SKKT 250

Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Precious metal pressure contacts for high reliability
- Thyristor with amplifying gate
- UL recognized, file no. E 63 532

Typical Applications*

- DC motor control (e. g. for machine tools)
- AC motor starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

| V_{RSM} V | V_{RRM}, V_{DRM} V | $I_{TRMS} = 420$ A (maximum value for continuous operation) $I_{TAV} = 250$ A (sin. 180; $T_c = 85$ °C) | |
|----------------|-------------------------|--|--------------|
| 900 | 800 | SKKT 250/08E | SKKH 250/08E |
| 1300 | 1200 | SKKT 250/12E | SKKH 250/12E |
| 1700 | 1600 | SKKT 250/16E | SKKH 250/16E |
| 1900 | 1800 | SKKT 250/18E | SKKH 250/18E |

| Symbol | Conditions | Values | Units |
|------------------|---|------------------------|------------------|
| I_{TAV} | sin. 180; $T_c = 85$ (100) °C; | 250 (178) | A |
| I_D | P16/200F; $T_a = 35$ °C; B2/B6 | 450 / 585 | A |
| I_{RMS} | P16/200F; $T_a = 35$ °C; W1 / W3 | 566 / 3 * 471 | A |
| I_{TSM} | $T_{vj} = 25$ °C; 10 ms | 9000 | A |
| | $T_{vj} = 130$ °C; 10 ms | 8000 | A |
| i^2t | $T_{vj} = 25$ °C; 8,3 ... 10 ms | 405000 | A ² s |
| | $T_{vj} = 130$ °C; 8,3 ... 10 ms | 320000 | A ² s |
| V_T | $T_{vj} = 25$ °C; $I_T = 750$ A | max. 1,4 | V |
| $V_{T(TO)}$ | $T_{vj} = 130$ °C | max. 0,925 | V |
| r_T | $T_{vj} = 130$ °C | max. 0,45 | mΩ |
| I_{DD}, I_{RD} | $T_{vj} = 130$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$ | max. 85 | mA |
| t_{gd} | $T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs | 1 | μs |
| t_{gr} | $V_D = 0,67 * V_{DRM}$ | 2 | μs |
| $(di/dt)_{cr}$ | $T_{vj} = 130$ °C | max. 250 | A/μs |
| $(dv/dt)_{cr}$ | $T_{vj} = 130$ °C | max. 1000 | V/μs |
| t_q | $T_{vj} = 130$ °C | 50 ... 150 | μs |
| I_H | $T_{vj} = 25$ °C; typ. / max. | 150 / 500 | mA |
| I_L | $T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max. | 300 / 2000 | mA |
| V_{GT} | $T_{vj} = 25$ °C; d.c. | min. 3 | V |
| I_{GT} | $T_{vj} = 25$ °C; d.c. | min. 200 | mA |
| V_{GD} | $T_{vj} = 130$ °C; d.c. | max. 0,25 | V |
| I_{GD} | $T_{vj} = 130$ °C; d.c. | max. 10 | mA |
| $R_{th(j-c)}$ | cont.; per thyristor / per module | 0,14 / 0,07 | K/W |
| $R_{th(j-c)}$ | sin. 180; per thyristor / per module | 0,15 / 0,075 | K/W |
| $R_{th(j-c)}$ | rec. 120; per thyristor / per module | 0,165 / 0,083 | K/W |
| $R_{th(c-s)}$ | per thyristor / per module | 0,04 / 0,02 | K/W |
| T_{vj} | | - 40 ... + 130 | °C |
| T_{stg} | | - 40 ... + 130 | °C |
| V_{isol} | a. c. 50 Hz; r.m.s.; 1 s / 1 min. | 3600 / 3000 | V~ |
| M_s | to heatsink | 5 ± 15 % ¹⁾ | Nm |
| M_t | to terminals | 9 ± 15 % | Nm |
| a | | 5 * 9,81 | m/s ² |
| m | approx. | 600 | g |
| Case | SKKT | A 73b | |
| | SKKH | A 76b | |



SKKT

SKKH

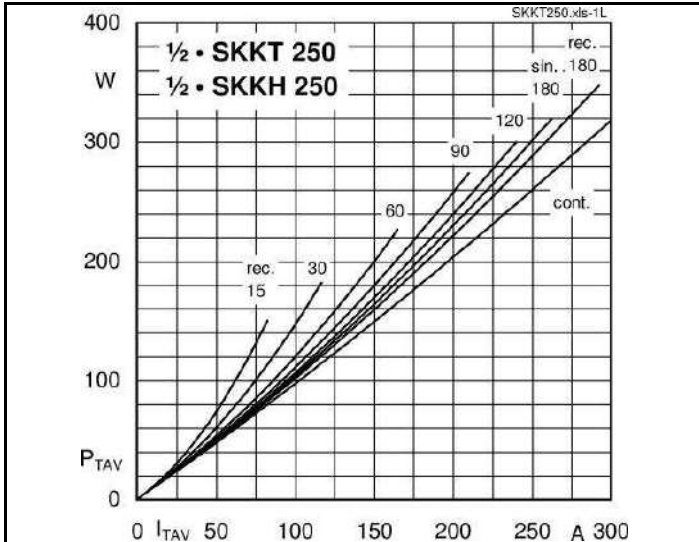


Fig. 1L Power dissipation per thyristor vs. on-state current

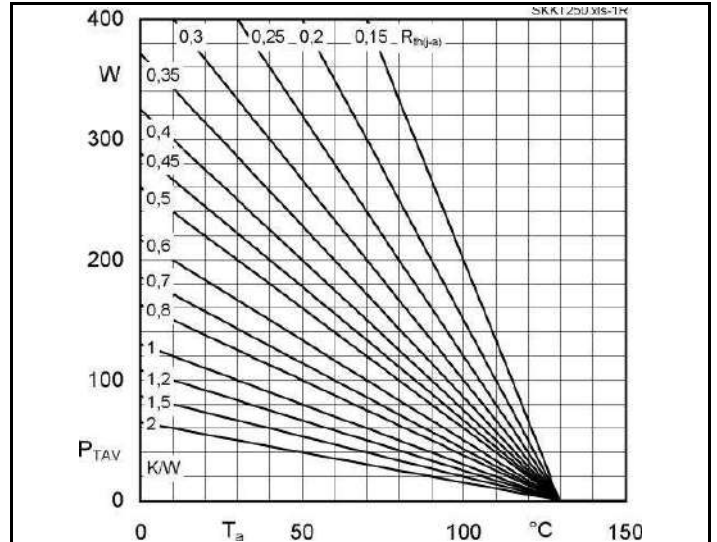


Fig. 1R Power dissipation per thyristor vs. ambient temp.

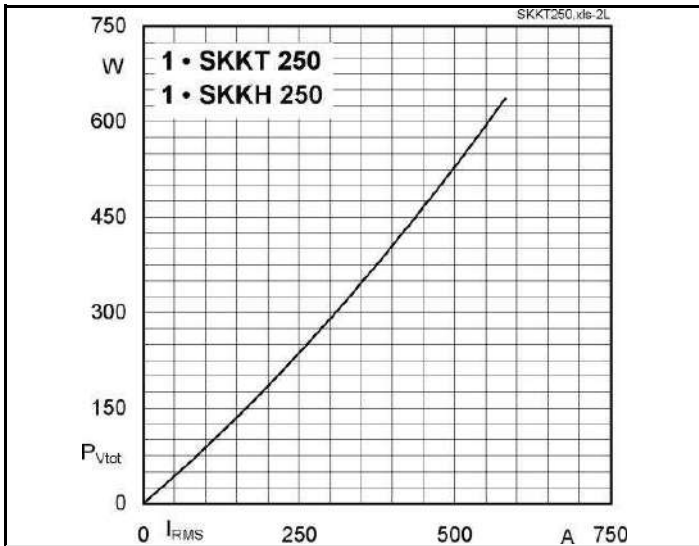


Fig. 2L Power dissipation per module vs. rms current

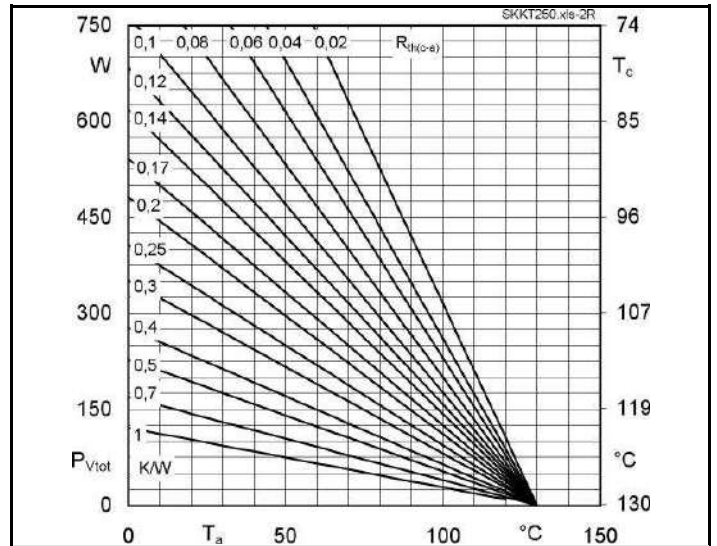


Fig. 2R Power dissipation per module vs. case temp.

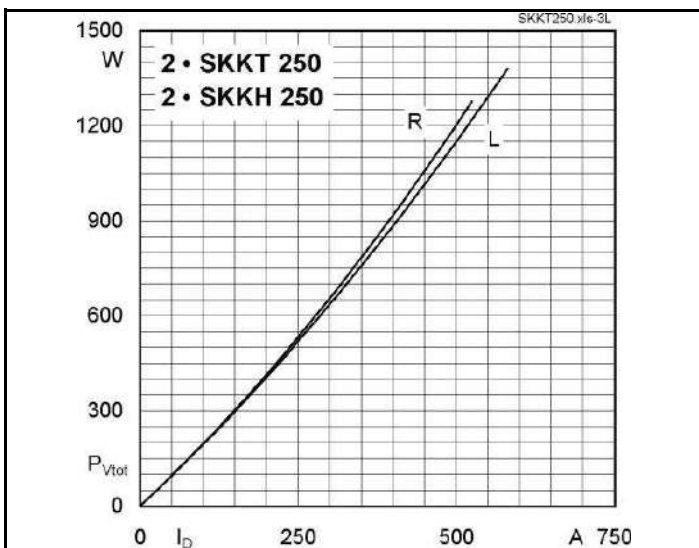


Fig. 3L Power dissipation of two modules vs. direct current

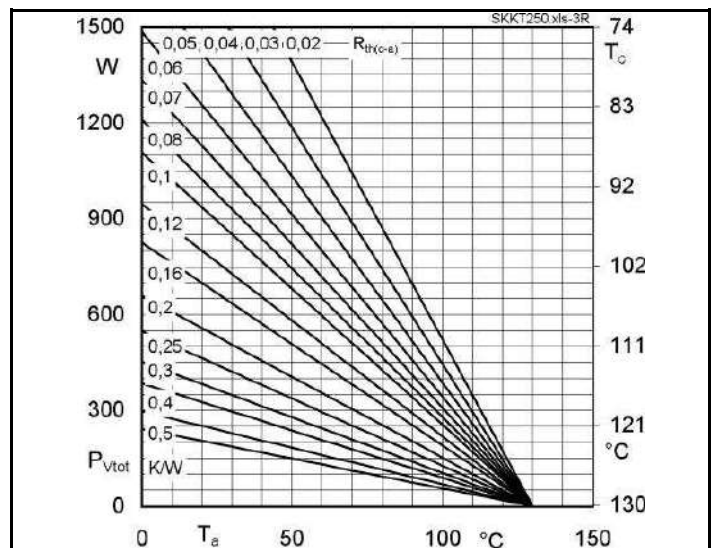
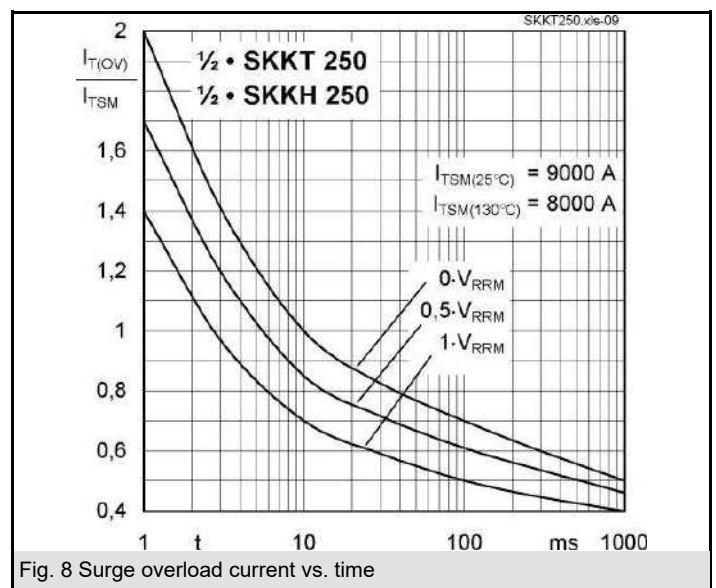
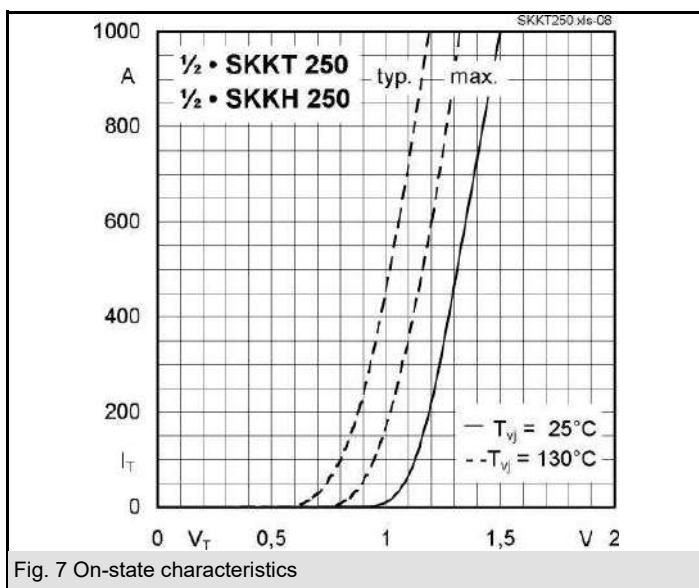
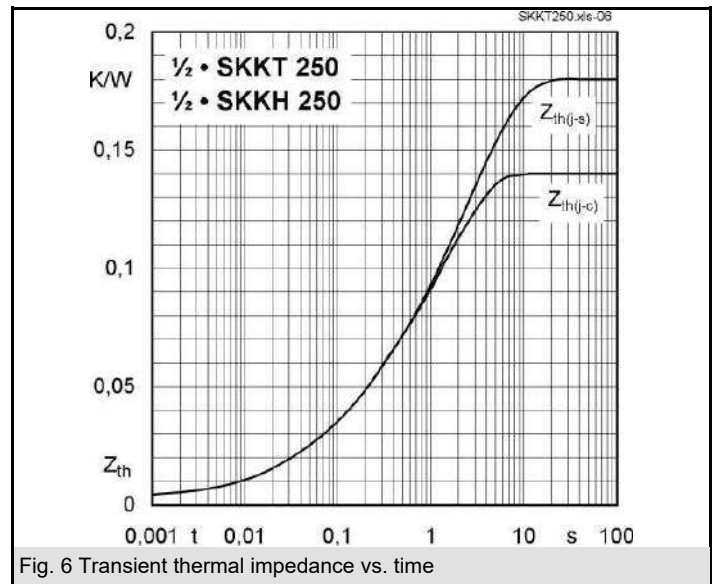
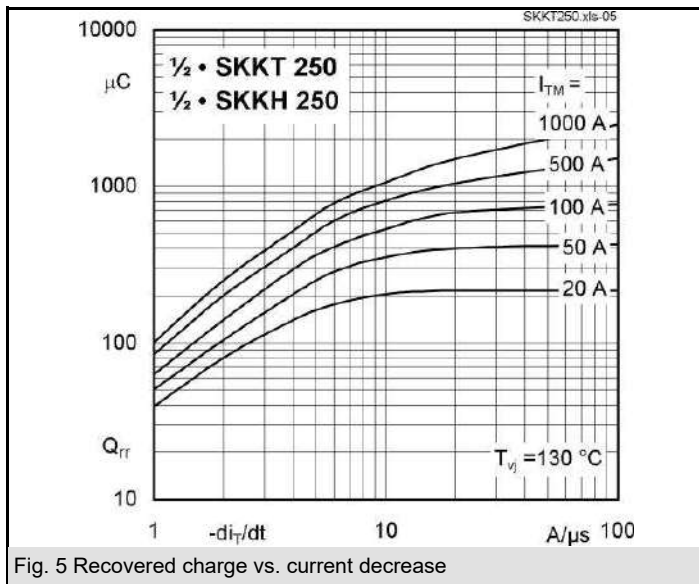
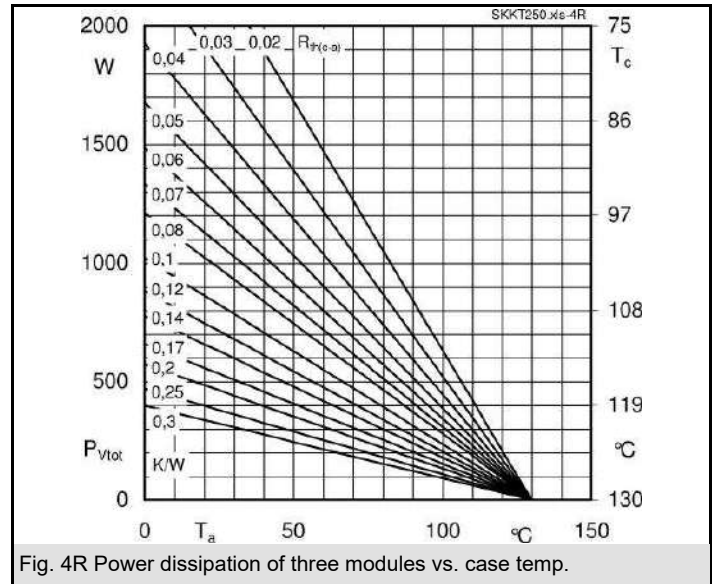
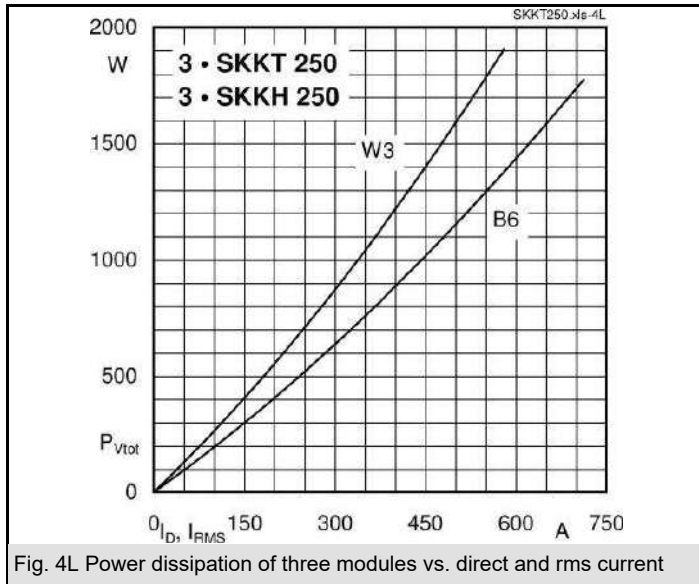


Fig. 3R Power dissipation of two modules vs. case temp.

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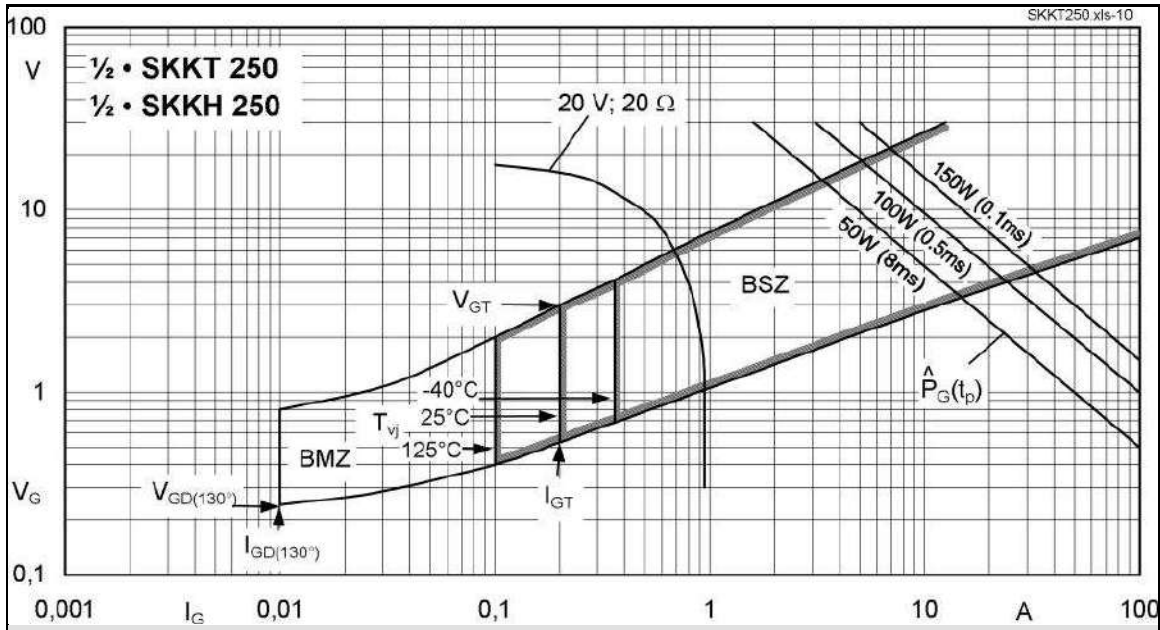
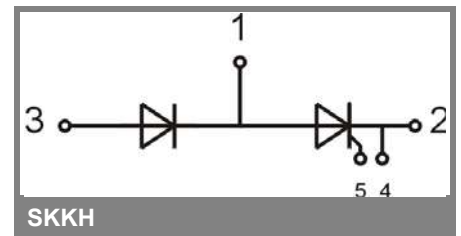
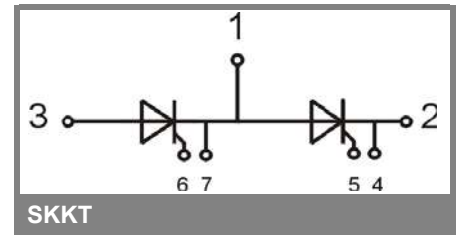
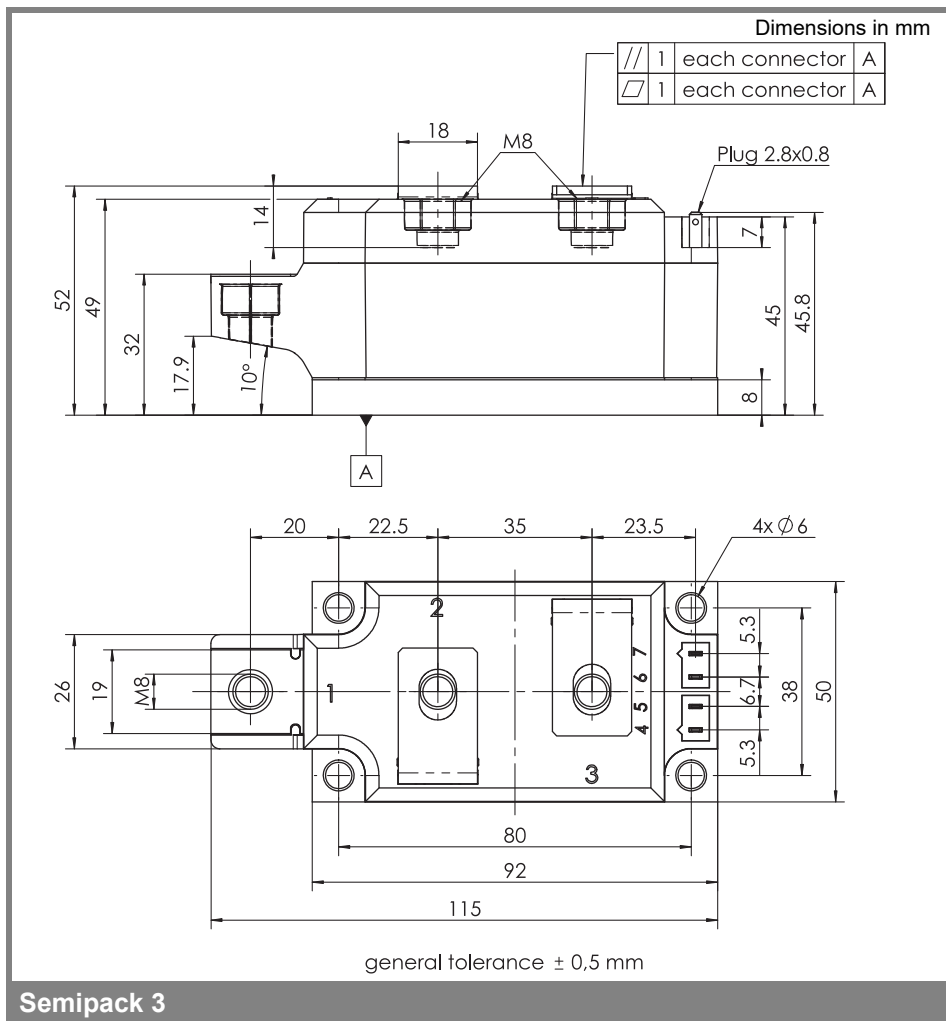


Fig. 9 Gate trigger characteristics



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

***IMPORTANT INFORMATION AND WARNINGS**

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